

### Features

- High voltage capability
- Very high switching speed

### Applications

Four lamp electronic ballast for:

- 120 V mains in push-pull configuration
- 277 V mains in half bridge current feed configuration

### Description

This is a high voltage fast switching NPN power transistor manufactured in multi epitaxial planar technology. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA.

Thanks to an increased intermediate layer, it has an intrinsic ruggedness which enables the transistor to withstand a high collector current level during breakdown condition, without using the Transil™ protection usually necessary in typical converters for lamp ballast.

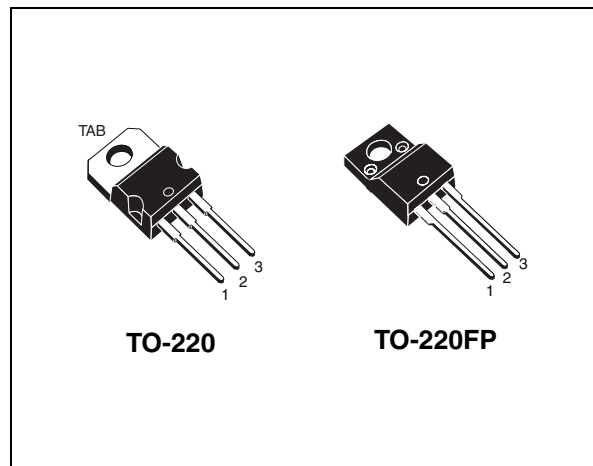


Figure 1. Internal schematic diagram

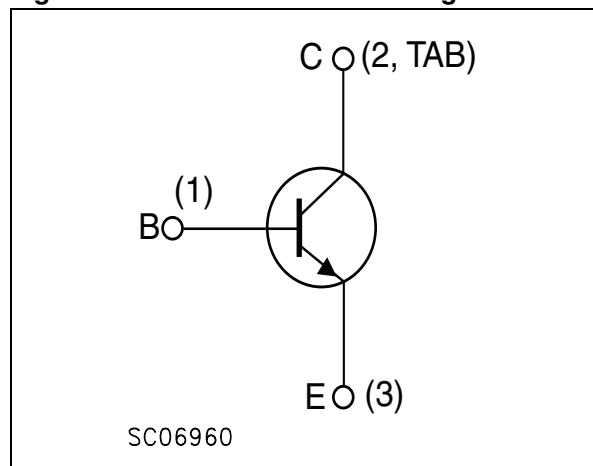


Table 1. Device summary

Order codes	Marking	Package	Packaging
BUL1102E	BUL1102E	TO-220	Tube
BUL1102EFP	BUL1102EFP	TO-220FP	Tube

# 1 Absolute maximum ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CES}$	Collector-emitter voltage ( $V_{BE} = 0$ )	1100	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )	450	V
$V_{EBO}$	Emitter-base voltage ( $I_C = 0$ )	12	V
$I_C$	Collector current	4	A
$I_{CM}$	Collector peak current ( $t_P < 5$ ms)	8	A
$I_B$	Base current	2	A
$I_{BM}$	Base peak current ( $t_P < 5$ ms)	4	A
$P_{TOT}$	BUL1102E total dissipation at $T_C = 25^\circ\text{C}$	70	W
	BUL1102EFP total dissipation at $T_C = 25^\circ\text{C}$	30	
$V_{ISO}$	BUL1102EFP insulation withstand voltage (RMS) from all three leads to external heatsink	1500	V
$T_{STG}$	Storage temperature	-65 to 150	$^\circ\text{C}$
$T_J$	Max. operating junction temperature	150	$^\circ\text{C}$

**Table 3. Thermal data**

Symbol	Parameter	Value	Unit
$R_{thJC}$	BUL1203E thermal resistance junction-case	1.8	$^\circ\text{C}/\text{W}$
	BUL1203EFP thermal resistance junction-case	4.2	$^\circ\text{C}/\text{W}$

## 2 Electrical characteristics

( $T_J = 25\text{ °C}$ ; unless otherwise specified)

**Table 4. Electrical characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{CES}$	Collector cut-off current ( $V_{BE} = 0$ )	$V_{CE} = 1100\text{ V}$			100	$\mu\text{A}$
$I_{EBO}$	Emitter cut-off current ( $I_C = 0$ )	$V_{EB} = 12\text{ V}$			1	mA
$V_{CEO(sus)}^{(1)}$	Collector-emitter sustaining voltage ( $I_B = 0$ )	$I_C = 100\text{ mA}$	450			V
$V_{CE(sat)}^{(1)}$	Collector-emitter saturation voltage	$I_C = 2\text{ A}$ $I_B = 400\text{ mA}$			1.5	V
$V_{BE(sat)}^{(1)}$	Base-emitter saturation voltage	$I_C = 2\text{ A}$ $I_B = 400\text{ mA}$			1.5	V
$h_{FE}^{(1)}$	DC current gain	$I_C = 250\text{ mA}$ $V_{CE} = 5\text{ V}$ $I_C = 2\text{ A}$ , $V_{CE} = 5\text{ V}$ for BUL1102E $I_C = 2\text{ A}$ $V_{CE} = 5\text{ V}$ for BUL1102EFP	35 12 12		70 20 23	
$t_s$ $t_f$	Resistive load Storage time Fall time	$I_C = 2.5\text{ A}$ $V_{CC} = 250\text{ V}$ $I_{B1} = 0.5\text{ A}$ $I_{B2} = 1\text{ A}$ $T_P = 30\text{ }\mu\text{s}$ (see <a href="#">Figure 14</a> )			2.5 300	$\mu\text{s}$ ns
$E_{ar}$	Avalanche energy	$L = 2\text{ mH}$ $C = 1.8\text{ nF}$ $I_{BR} \leq 2.5\text{ A}$ $25\text{ °C} < T_C < 125\text{ °C}$ (see <a href="#">Figure 12</a> )	6			mJ

1. Pulse test: pulse duration  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .

## 2.1 Typical characteristics (curves)

Figure 2. BUL1102E safe operating area

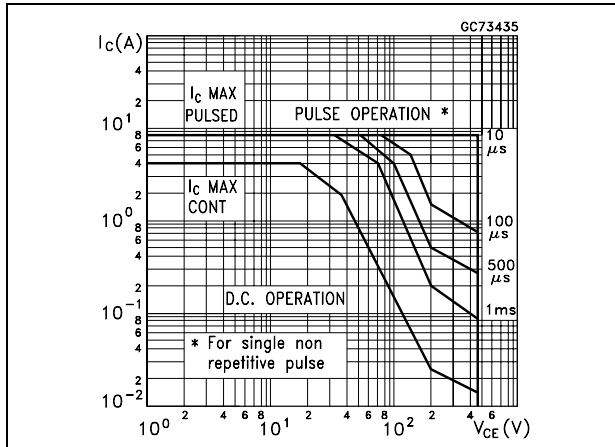


Figure 3. BUL1102EFP safe operating area

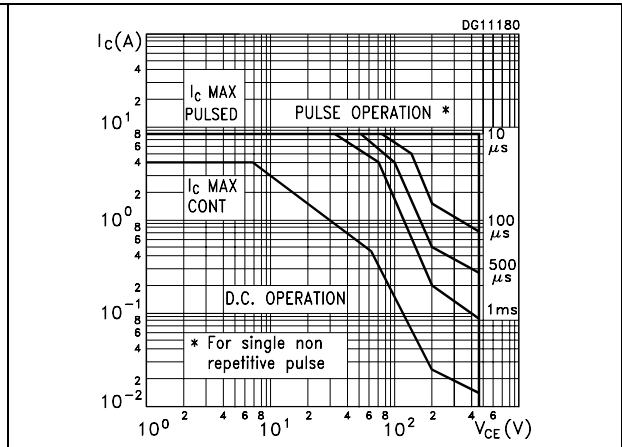


Figure 4. Derating curve

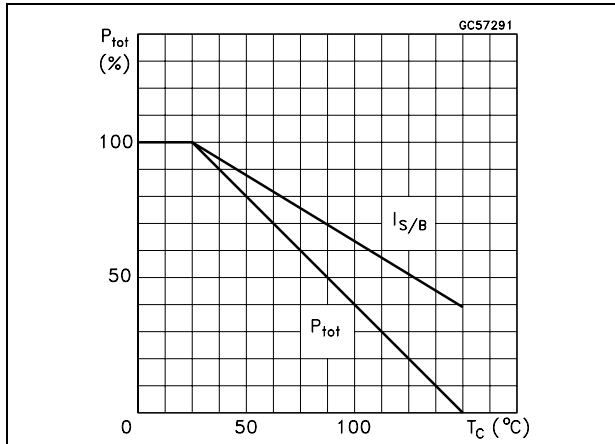


Figure 5. DC current gain (Vce = 1 V)

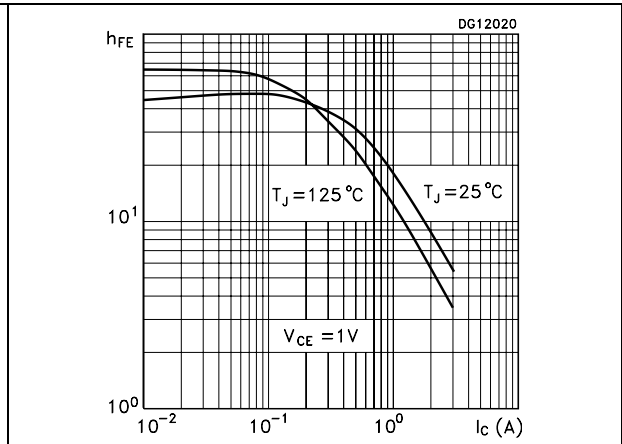


Figure 6. DC current gain (Vce = 5 V)

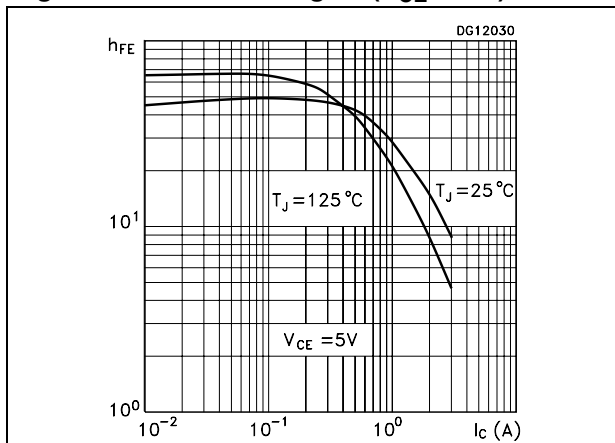


Figure 7. Collector emitter saturation voltage

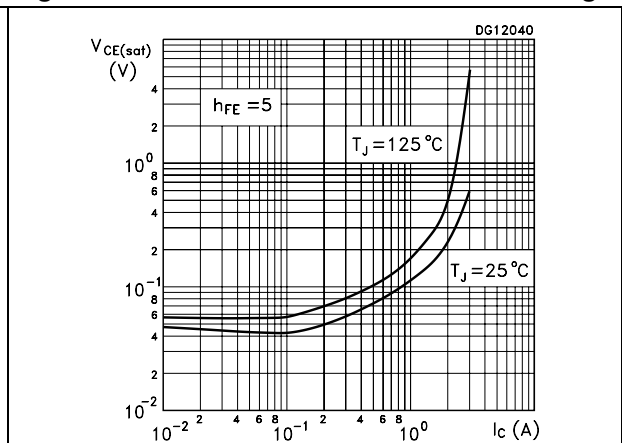


Figure 8. Base emitter saturation voltage

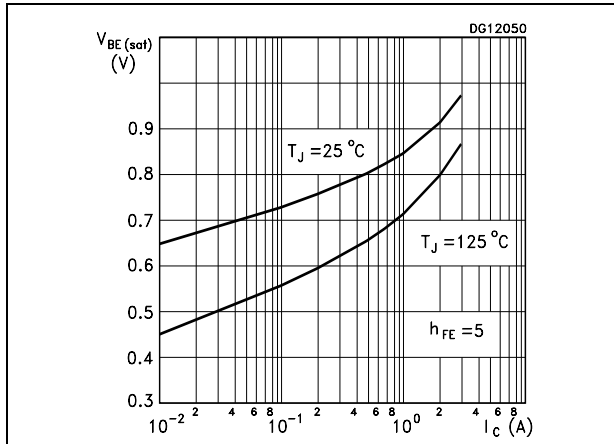


Figure 9. Resistive load switching times

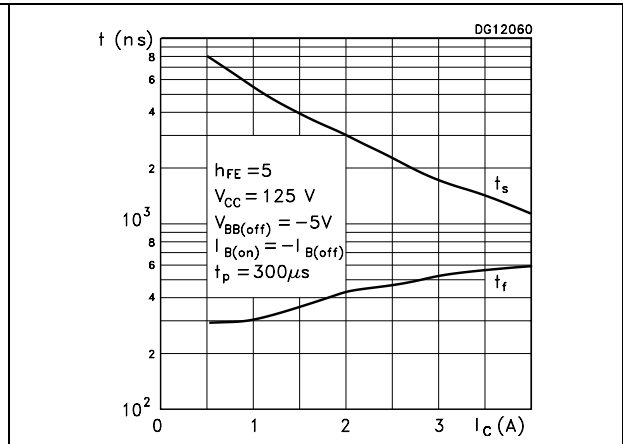


Figure 10. Inductive load switching times

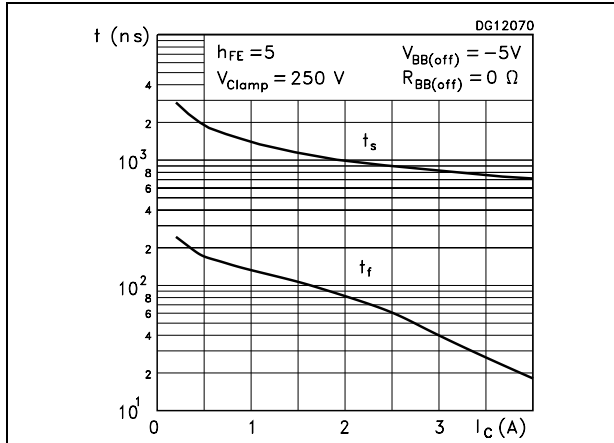


Figure 11. Reverse biased SOA

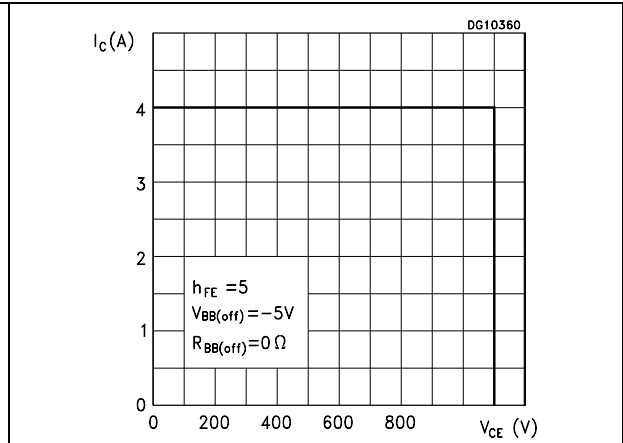


Figure 12. Energy rating test circuit

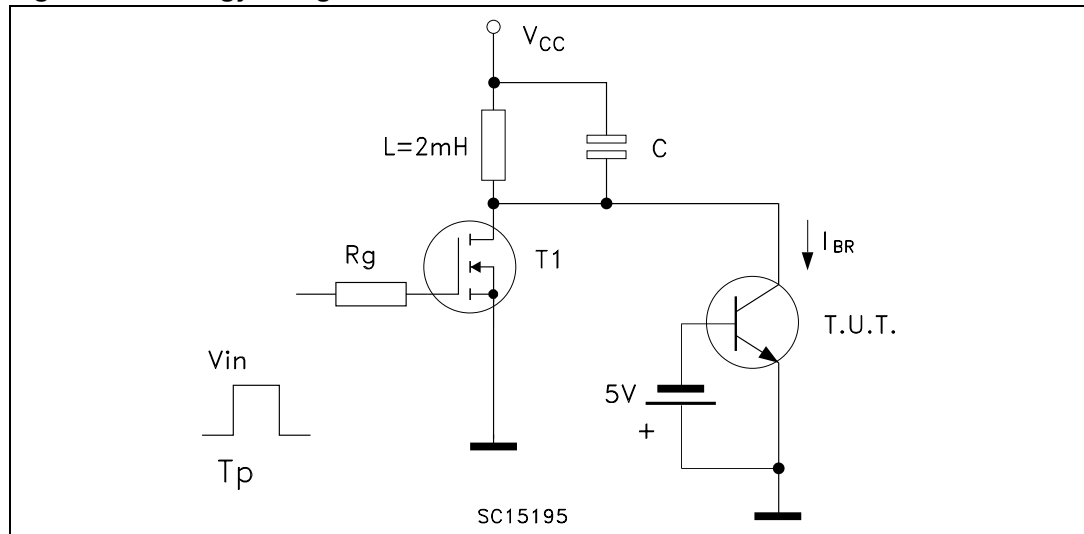


Figure 13. Inductive load switching test circuit

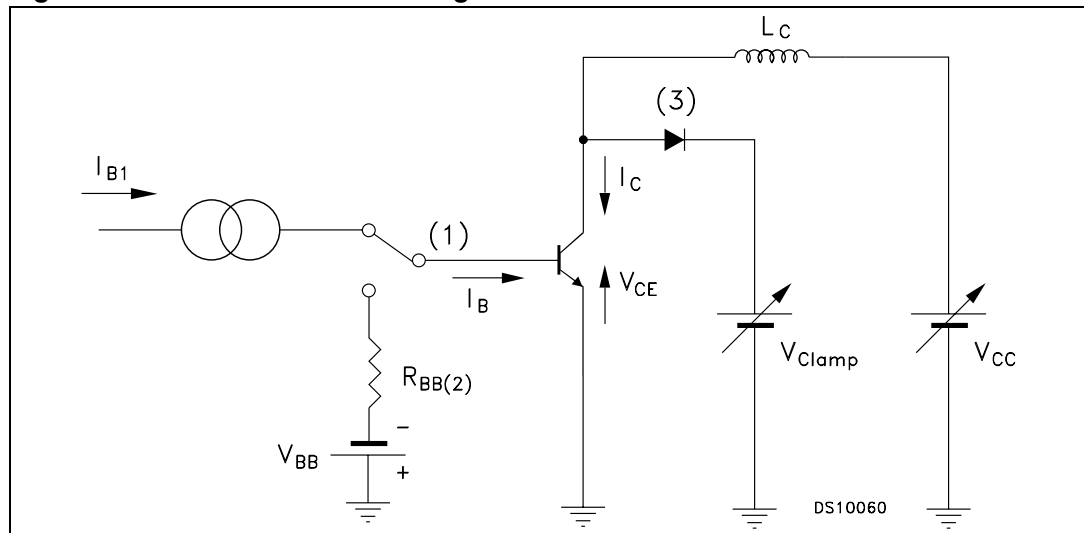
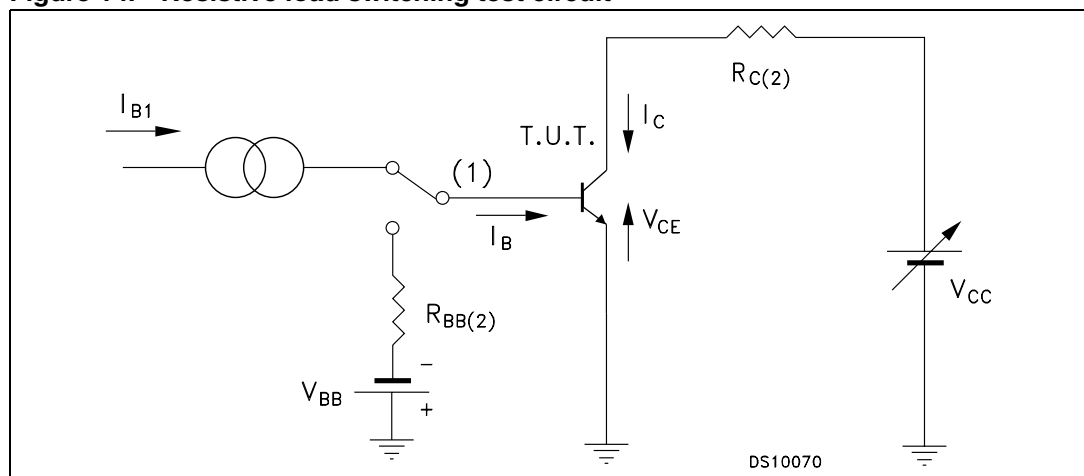


Figure 14. Resistive load switching test circuit



### 3 Package mechanical data

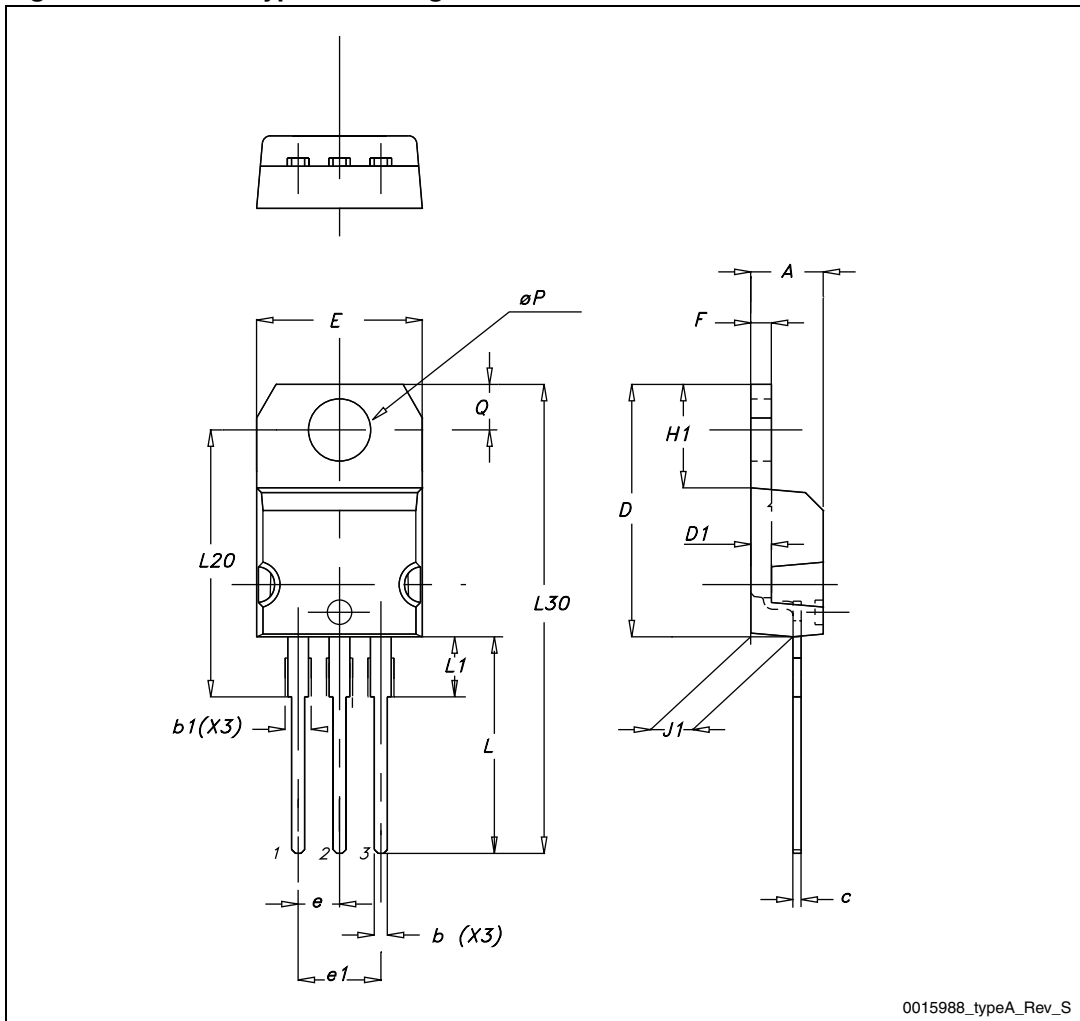
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

Table 5. TO-220 type A mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95



Figure 15. TO-220 type A drawing

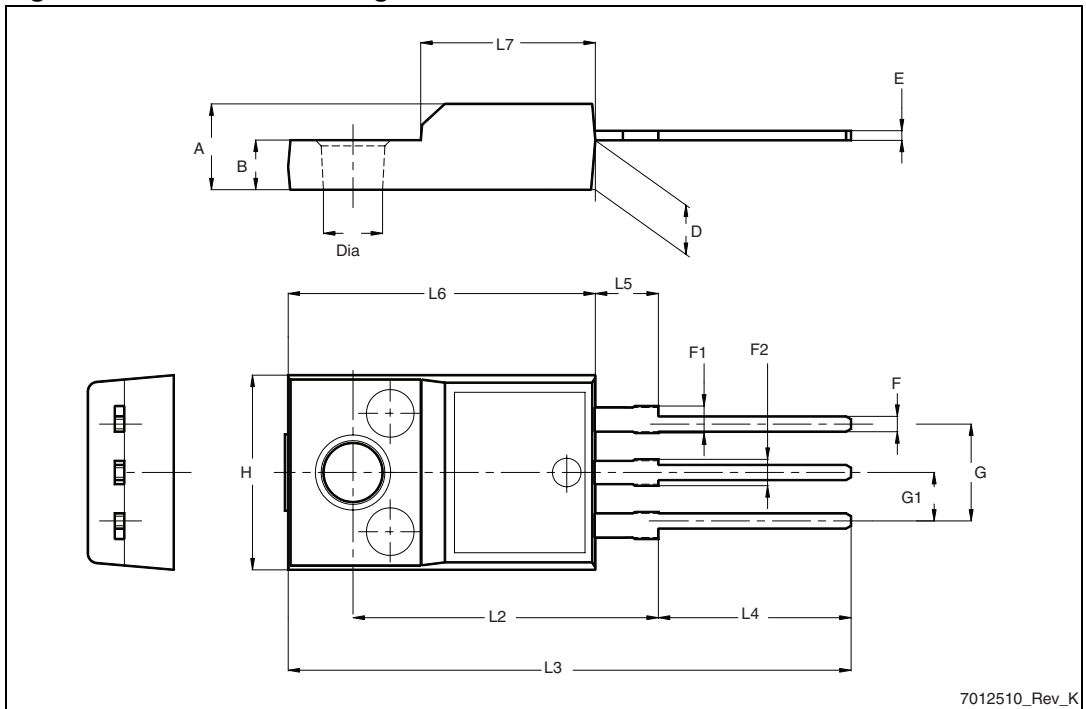


0015988\_typeA\_Rev\_S

Table 6. TO-220FP mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.4		4.6
B	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.70
G	4.95		5.2
G1	2.4		2.7
H	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2

Figure 16. TO-220FP drawing



7012510\_Rev\_K

## 4 Revision history

**Table 7. Document revision history**

Date	Revision	Changes
17-Jan-2008	3	
24-Mar-2011	4	Inserted BUL1102EFP order code in TO-220FP package
15-Feb-2012	5	DC current gain values in <a href="#">Table 4</a> modified

**Please Read Carefully:**

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

**UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.**

**UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.**

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2012 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

[www.st.com](http://www.st.com)





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.